Vishay Semiconductors

High Performance Schottky Rectifier, 2 A

Anode

-0



- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-20MQ100NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES			
I _{F(AV)}	Rectangular waveform	2	А		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	120	А		
V _F	2 A _{pk} , T _J = 125 °C	0.72	V		
TJ	Range	-55 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-20MQ100NPbF	UNITS	
Maximum DC reverse voltage	V _R	100	V	
Maximum working peak reverse voltage	V _{RWM}	100	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current		50 % duty cycle at T_C = 113 °C, r On PC board 9 mm ² island (0.013	U U	2.1	А
See fig. 4	IF(AV)	50 % duty cycle at T_C = 116 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		2	A
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А
See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	30	~
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 0.5 \text{ A}, L = 8 \text{ mH}$		1.0	mJ
Repetitive avalanche current	I _{AR}			0.5	А

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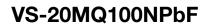
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PRODUCT SUMMARY				
Package	DO-214AC (SMA)			
I _{F(AV)}	2 A			
V _R	100 V			
V _F at I _F	0.72 V			
I _{RM} max.	1 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	1.0 mJ			







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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		2 A		0.91	V
		1.5 A	T _J = 25 °C	0.85	
Maximum forward voltage drop	V (1)	1 A		0.78	
See fig. 1	V _{FM} ⁽¹⁾	2 A		0.72	
		1.5 A	T _J = 125 °C	0.68	
		1 A		0.63	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Patad V	0.1	mA
See fig. 2	IRM (17	T _J = 125 °C	$ V_R = Rated V_R$	1	
Threshold voltage	V _{F(TO)}	$T_J = T_J maximum$		0.52	V
Forward slope resistance	r _t			78.4	mΩ
Typical junction capacitance	CT	$V_R = 10 V_{DC}$, $T_J = 25 $ °C, test signal = 1 MHz		38	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approvimeto weight			0.07	g
Approximate weight			0.002	oz.
Marking device		Case style DO-214AC (SMA) (similar D-64)	2	J

Note

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$



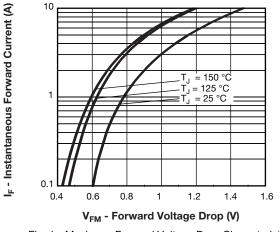


Fig. 1 - Maximum Forward Voltage Drop Characteristics

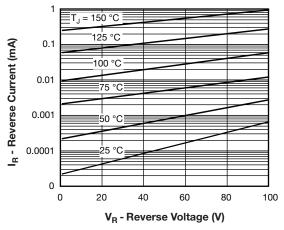


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

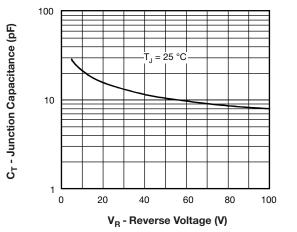
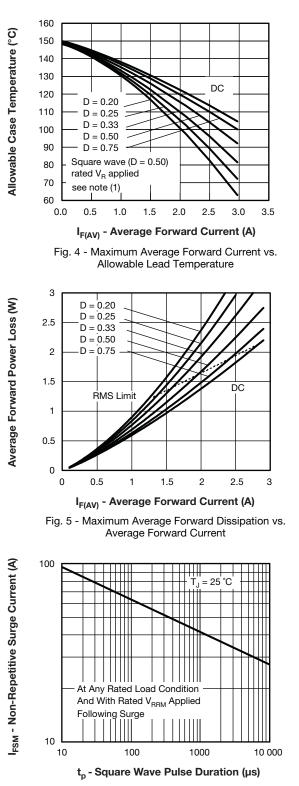
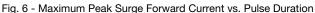


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

VS-20MQ100NPbF

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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

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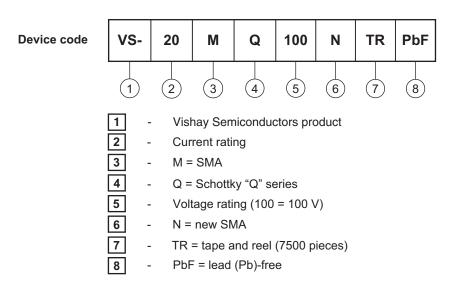
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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)				
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-20MQ100NTRPbF	5AT	7500	13" diameter plastic tape and reel	

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95400	
Part marking information	www.vishay.com/doc?95403	
Packaging information	www.vishay.com/doc?95404	



Outline Dimensions

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SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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